## NSN 5962-01-352-3557

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View Online at https://aerobasegroup.com/nsn/5962-01-352-3557

view Offiline at https://defobasegroup.com/hsr//0902-01-002-0007	
Body Length:	
1.490 inches	
Body Width:	
Between 0.500 inches and 0.610 inches	
Body Height:	
0.217 inches	
Operating Tempurature Range:	
-55.0/+125.0 degrees celsius	
Storage Tempurature Range:	
-65.0/+150.0 degrees celsius	
End Application:	
Radar set an/sps-4 (v) 7	
Features Provided:	
Hermetically sealed and burn in and monolithic and electrostatic sensitive	
Inclosure Material:	
Ceramic	
Inclosure Configuration:	
Dual-in-line	
Output Logic Form:	
Complementary-metal oxide-semiconductor logic	
Input Circuit Pattern:	
14 input	
Case Outline Source And Designator:	
D-10 mil-m-38510	
Current Rating Per Characteristic:	
150.00 milliamperes reverse current, dc absolute	
Terminal Surface Treatment:	
Solder	
Product Name:	
First-in/first-out memory	
Voltage Rating And Type Per Characteristic:	
-0.5 volts power source and 7.0 volts power source	
Capitance Rating Per Characteristic:	
8.00 input picofarads and 12.00 output picofarads	
Time Rating Per Chacteristic:	
120.00 nanoseconds access	
Memory Device Type:	
First-in first-out	
Test Data Document:	
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, e	etc.)
Terminal Type And Quantity:	

28 printed circuit

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Shelf Life:

N/a

**Unit Of Measure:** 

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Demilitarization:

Yes - demil/mli

Fiig:

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